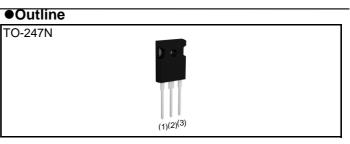


# SCT4036KEHR

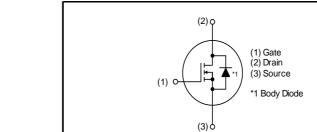
## Automotive Grade N-channel SiC power MOSFET

#### Datasheet

V <sub>DSS</sub>	1200V
R <sub>DS(on)</sub> (Typ.)	36mΩ
$I_{D}^{*1}$	43A
P <sub>D</sub>	176W



#### •Inner circuit



#### Features

- 1) Qualified to AEC-Q101
- 2) Low on-resistance
- 3) Fast switching speed
- 4) Fast reverse recovery
- 5) Easy to parallel
- 6) Simple to drive
- 7) Pb-free lead plating ; RoHS compliant

#### Application

- Automobile
- Switch mode power supplies

#### •Packaging specifications

	Packing	Tube
	Reel size (mm)	-
Tuno	Tape width (mm)	-
Туре	Basic ordering unit (pcs)	30
	Taping code	C11
	Marking	SCT4036KE

#### • Absolute maximum ratings ( $T_c = 25^{\circ}C$ )

Parameter		Symbol	Value	Unit
Drain - source voltage		V <sub>DSS</sub>	1200	V
Continuous drain and source current $V_{GS} = V_{GS_{on}}$		, , *1	43	А
$T_c = 100^{\circ}C$	$v_{GS} = v_{GS_{on}}$	Ι <sub>D</sub> , Ι <sub>S</sub> <sup>*1</sup>	30	А
Pulsed drain current	$V_{GS} = V_{GS\_on}$	I <sub>D,pulse</sub> *2	84	А
Body diode pulsed forward current	$V_{GS} = 0 V$	<sup>*3</sup> S,pulse	43	А
Body diode surge forward current	$V_{GS} = 0 V$	4 <sup>*4</sup> S,pulse	84	А
Gate - source voltage (DC)		$V_{GSS_{DC}}$	-4 to +21	V
Gate - source surge voltage ( $t_{surge} < 300$	)ns)	$V_{GSS\_surge}$ *5	-4 to +23	V
Recommended turn-on gate - source dr	ive voltage	V <sub>GS_on</sub> *6	+15 to +18	V
Recommended turn-off gate - source drive voltage		$V_{GS\_off}$	0	V
Virtual junction temperature		$T_{vj}$	175	°C
Range of storage temperature		T <sub>stg</sub>	-40 to +175	°C

## •Electrical characteristics ( $T_{vj}$ = 25°C unless otherwise specified)

Deremeter	Symbol Conditions -		Values			L locit
Parameter			Min.	Тур.	Max.	Unit
Drain - Source breakdown	V	$V_{GS} = 0 V, I_{D} = 9.2 mA$				V
voltage	V (BR)DSS	$T_{vj} = 25^{\circ}C$	1200	-	-	v
		$V_{GS} = 0 V, V_{DS} = 1200V$				
Zero Gate voltage Drain current	I <sub>DSS</sub>	T <sub>vj</sub> = 25°C	-	1	80	μA
		T <sub>vj</sub> = 150°C	-	10	-	
Gate - Source leakage current	I <sub>GSS+</sub>	$V_{GS} = +21V$ , $V_{DS} = 0V$	-	-	100	nA
Gate - Source leakage current		$V_{GS} = -4V  , V_{DS} = 0V$	-	-	-100	nA
Gate threshold voltage	$V_{GS(th)}$ *7	$V_{DS} = 10V, I_{D} = 11.1mA$	2.8	-	4.8	V
		$V_{GS} = 18V, I_{D} = 21A$				
Static Drain - Source on - state resistance	${\sf R}_{\sf DS(on)}$ *8	T <sub>vj</sub> = 25°C	-	36	47	mΩ
		T <sub>vj</sub> = 150°C	-	72	-	
Gate input resistance	R <sub>G</sub>	f = 1MHz, open drain	-	1	-	Ω

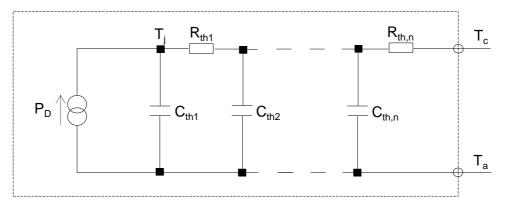
#### Thermal resistance

Parameter	Symbol	Values			Unit	
Falameter	Symbol	Min.	Тур.	Max.	Offic	
Thermal resistance, junction - case	${\sf R_{thJC}}^{*9}$	-	0.65	0.85	K/W	

### •Typical Transient Thermal Characteristics

Symbol	Value	Unit
R <sub>th1</sub>	1.1 ×10 <sup>-1</sup>	
R <sub>th2</sub>	2.5 ×10 <sup>-1</sup>	K/W
R <sub>th3</sub>	2.9 ×10 <sup>-1</sup>	

Symbol	Value	Unit
C <sub>th1</sub>	5.8 ×10 <sup>-4</sup>	
C <sub>th2</sub>	2.3 ×10 <sup>-3</sup>	Ws/K
C <sub>th3</sub>	1.1 ×10 <sup>-2</sup>	





# •Electrical characteristics (T<sub>vj</sub> = 25°C unless otherwise specified)

Deremeter	Cumbel Conditions	Values				
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Transconductance	g <sub>fs</sub> <sup>∗8</sup>	$V_{DS} = 10V, I_{D} = 21A$	-	11	-	S
Input capacitance	C <sub>iss</sub>	$V_{GS} = 0V$	-	2335	-	
Output capacitance	C <sub>oss</sub>	V <sub>DS</sub> = 800V	-	70	-	pF
Reverse transfer capacitance	C <sub>rss</sub>	f = 1MHz	-	5	-	
Effective output capacitance, energy related	C <sub>o(er)</sub>	$V_{GS} = 0V$ $V_{DS} = 0V$ to 800V	-	84	-	pF
Total Gate charge	Q <sub>g</sub> *8	$V_{DS} = 800V$	-	91	-	
Gate - Source charge	Q <sub>gs</sub> *8	I <sub>D</sub> = 21A V <sub>GS</sub> = 18V	-	20	-	nC
Gate - Drain charge	Q <sub>gd</sub> <sup>*8</sup>	See Fig. 1-1, 1-2.	-	24	-	
Turn - on delay time	t <sub>d(on)</sub> *8	$V_{DS} = 800V$ $I_{D} = 21A$	-	10	-	
Rise time	t <sub>r</sub> *8	V <sub>GS</sub> = +18V / 0V	-	28	-	2
Turn - off delay time	t <sub>d(off)</sub> *8	$R_G = 3.3\Omega$ , L = 250µH E <sub>on</sub> includes diode	-	31	-	ns
Fall time	t <sub>f</sub> *8	reverse recovery $L_{\sigma} = 50$ nH, $C_{\sigma} = 10$ pF	-	12	-	
Turn - on switching loss	E <sub>on</sub> *8	See Fig. 2-1, 2-2, 2-3.	-	480	-	1
Turn - off switching loss	E <sub>off</sub> *8		-	57	-	μJ



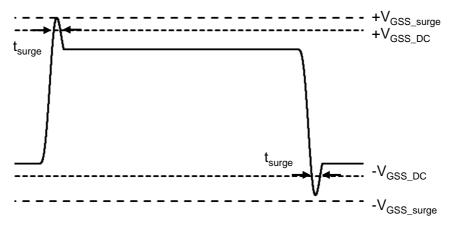
•Body diode electrical characteristics (Source-Drain) (T<sub>vi</sub> = 25°C unless otherwise specified)

Parameter	Symbol Conditions		Values			Unit
Farameter	Symbol	Conditions	Min.	Тур.	Max.	Offic
Forward voltage	$V_{SD}^{*8}$	$V_{GS} = 0V, I_D = 21A$	-	3.3	-	V
Reverse recovery time	t <sub>rr</sub> *8	$I_F = 21A$ $V_R = 800V$	-	20	-	ns
Reverse recovery charge	Q <sub>rr</sub> *8	di/dt = 2400A/µs	-	130	-	nC
Peak reverse recovery current	I <sub>rrm</sub> *8	$L_{\sigma} = 50$ nH, $C_{\sigma} = 10$ pF See Fig. 3-1, 3-2.	-	12	-	А

\*1 Limited by maximum  $T_{vj}$  and for Max.  $R_{thJC}$ .

- \*2 PW  $\leq$  10µs, Duty cycle  $\leq$  1%
- \*3 Only for body-diode, Repititive pulse, PW  $\leq$  500ns, Duty cycle  $\leq$  5%
- \*4 When used as a protective function, PW  $\leq$  10µs

\*5 Example of acceptable V<sub>GS</sub> waveform



- \*6 Please be advised not to use SiC-MOSFETs with  $V_{GS}$  below 10V as doing so may cause thermal runaway.
- \*7 Tested after applying  $V_{GS} = 21V$  for 100ms.

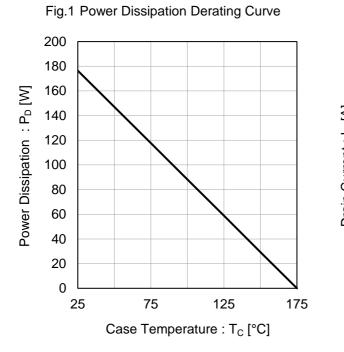
#### \*8 Pulsed

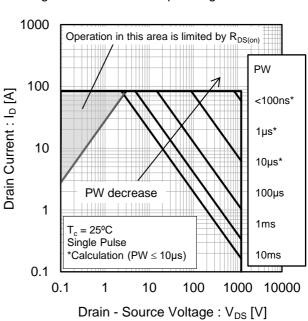
\*9 Measured conformable to JESD51-14.

See the application note "rthjc\_measurement\_and\_usage\_an-e.pdf". Link

 ${\tt URL: https://fscdn.rohm.com/en/products/databook/applinote/discrete/common/rthjc\_measurement\_and\_usage\_an-e.pdf}$ 







#### Fig.2 Maximum Safe Operating Area

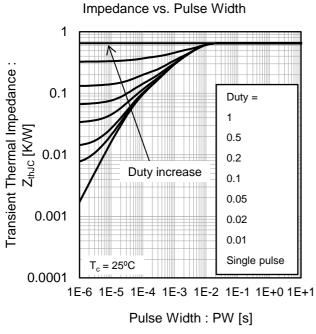
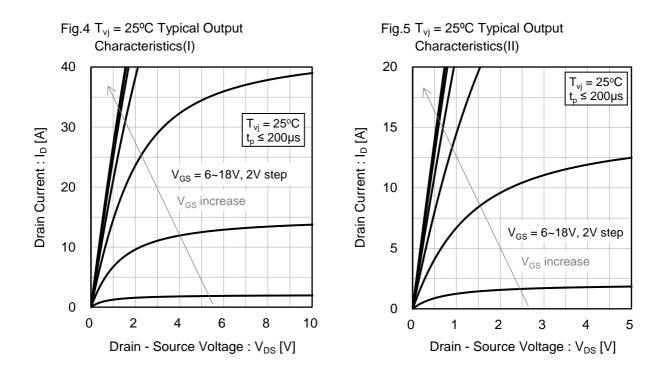
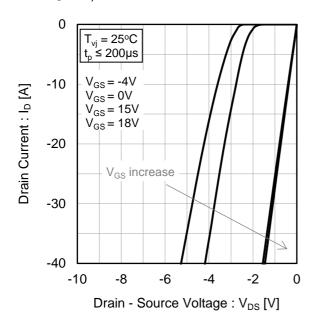


Fig.3 Typical Transient Thermal Impedance vs. Pulse Width

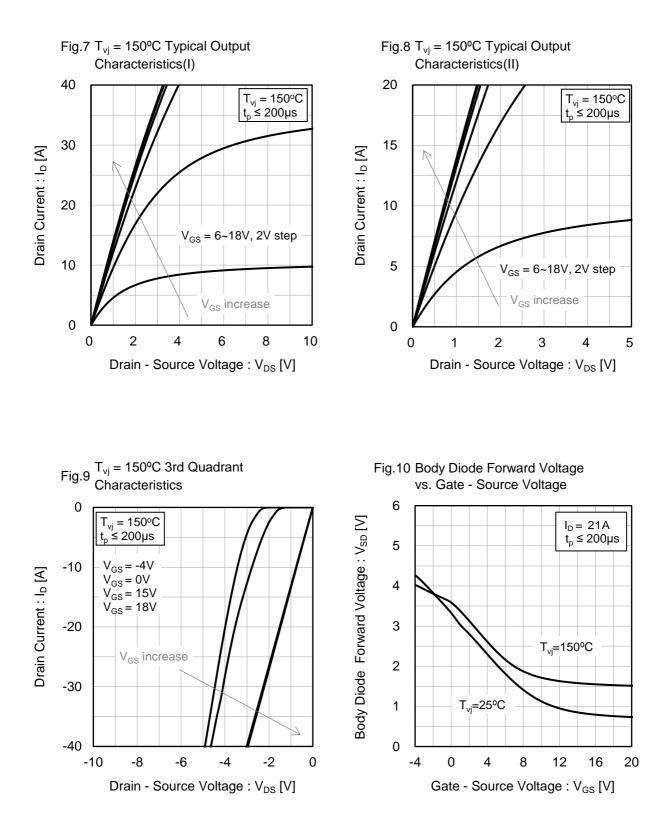




#### Fig.6 $T_{vj}$ = 25°C 3rd Quadrant Characteristics









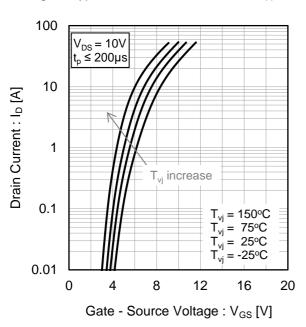
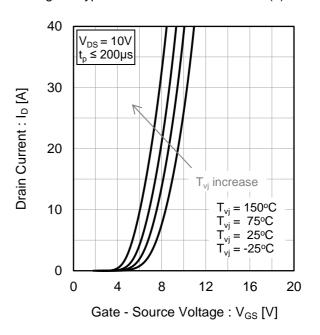


Fig.11 Typical Transfer Characteristics (I)

Fig.12 Typical Transfer Characteristics (II)



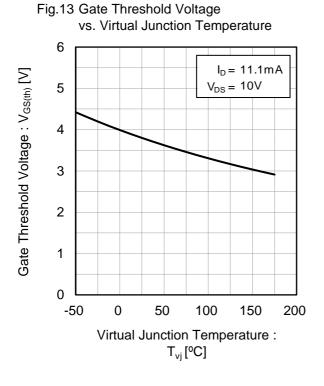
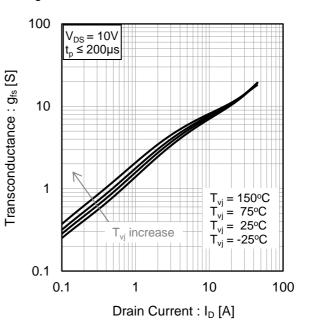
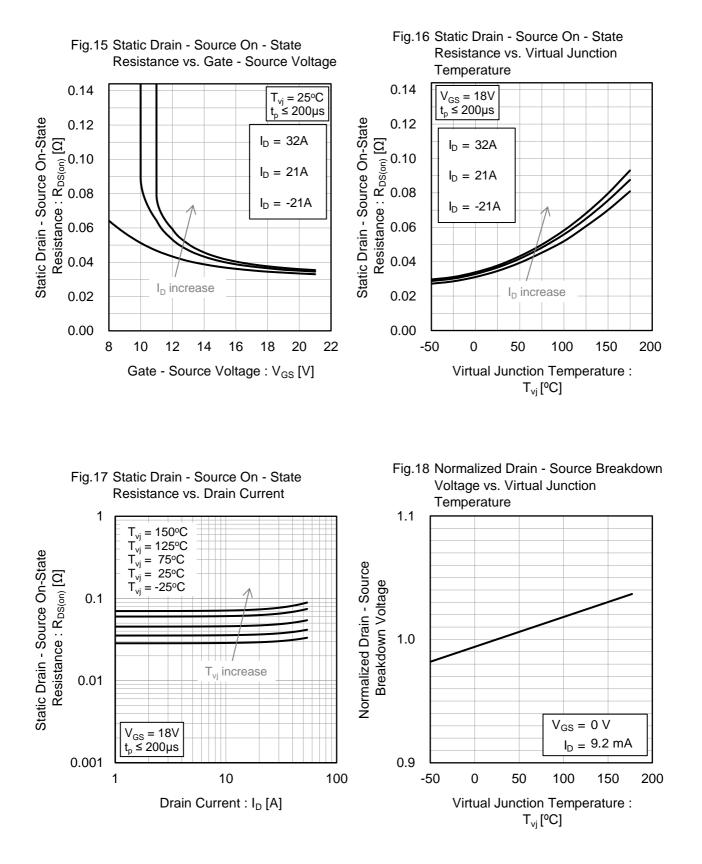


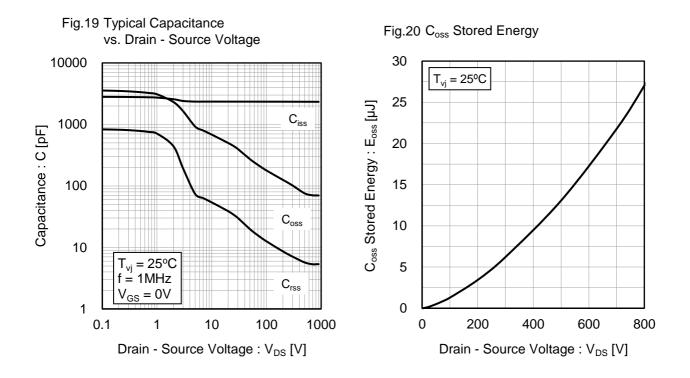
Fig.14 Transconductance vs. Drain Current



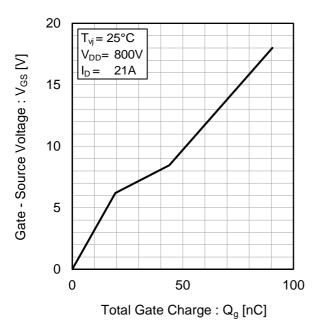






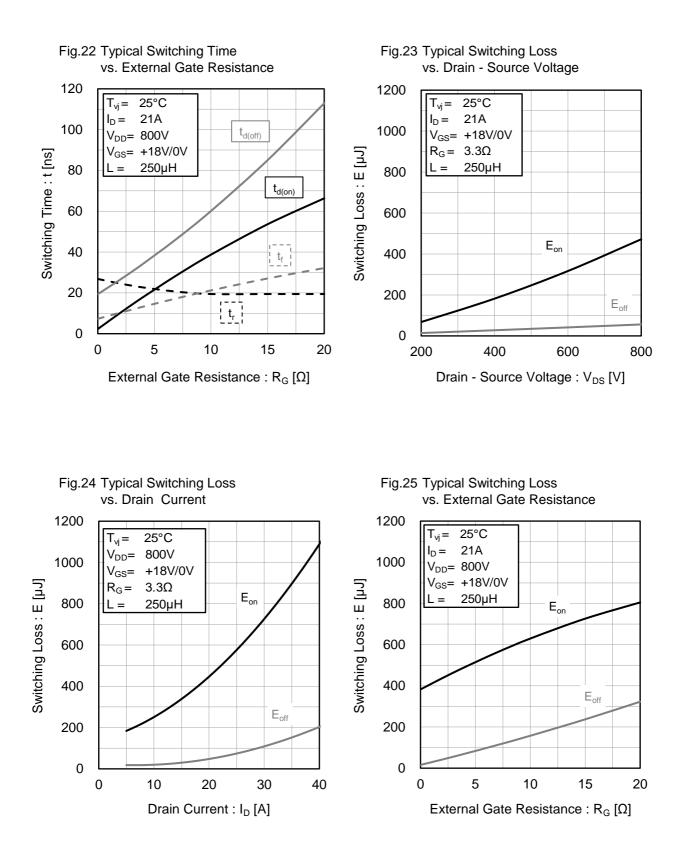


#### Fig.21 Dynamic Input Characteristics



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#### Measurement circuits and waveforms



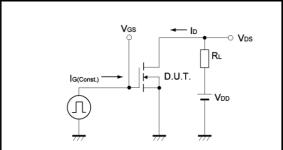


Fig.2-1 Switching Characteristics Measurement Circuit

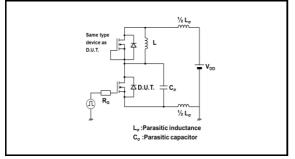


Fig.2-3 Waveforms for Switching Energy Loss

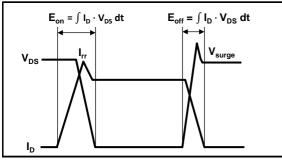
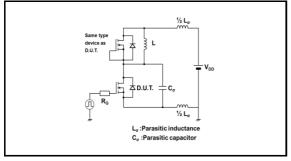
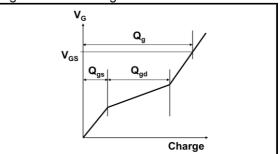


Fig.3-1 Reverse Recovery Time Measurement Circuit



#### Fig.1-2 Gate Charge Waveform





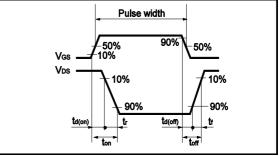
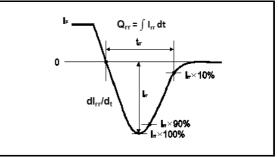
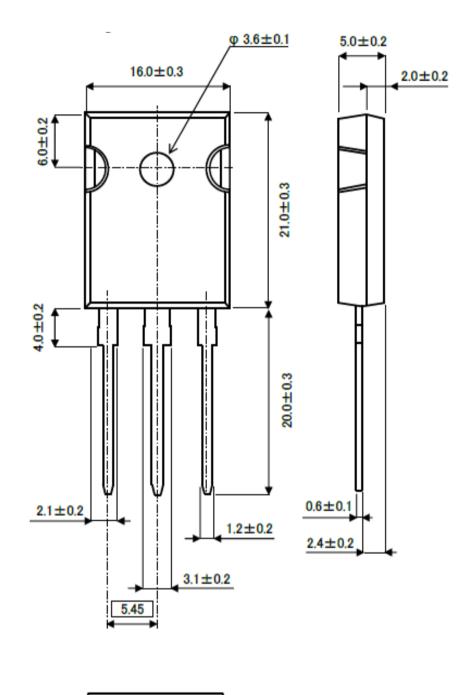


Fig.3-2 Reverse Recovery Waveform





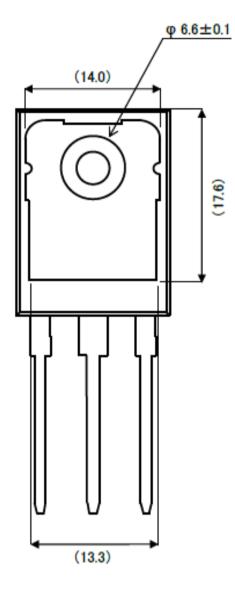
#### Package Dimensions





Unit: mm

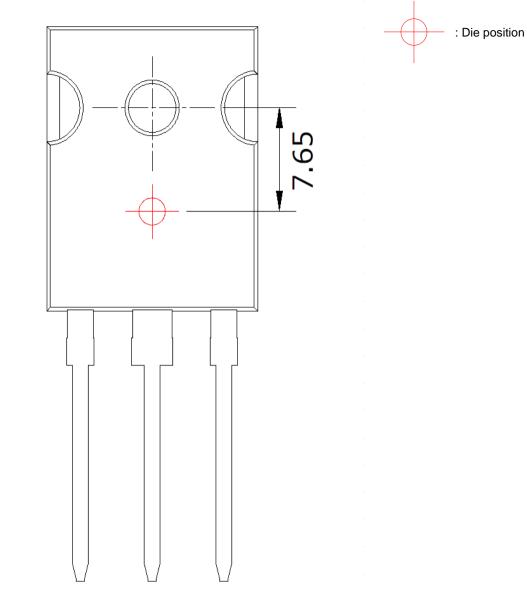




Unit: mm



#### Die Bonding Layout



•Front view of the packaging.

•Dimensions are design values.

·If the heat sink is to be installed, it should be in contact with the die bonding point.

Unit: mm



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